

## isc Silicon PNP Power Transistors

## 2SB696

#### **DESCRIPTION**

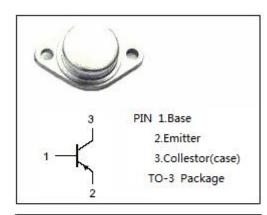
- · Collector-Emitter Breakdown Voltage-
  - : V<sub>(BR)CEO</sub>= -120V(Min)
- · High Current Capability
- Wide Area of Safe Operation
- Complement to Type 2SD732
- · Minimum Lot-to-Lot variations for robust device performance and reliable operation

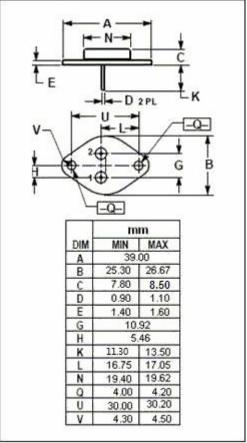


- · Designed for AF power amplifier applications.
- Recommended for output stage of 60W power amplifier.



SYMBOL	PARAMETER	VALUE	UNIT	
V <sub>CBO</sub>	Collector-Base Voltage	-150	V	
V <sub>CEO</sub>	Collector-Emitter Voltage	-120	V	
V <sub>EBO</sub>	Emitter-Base Voltage	-6	V	
Ic	Collector Current-Continuous	-8	А	
I <sub>CM</sub>	Emitter Current-Peak	-12	А	
Pc	Collector Power Dissipation @T <sub>C</sub> =25°C	80	W	
TJ	Junction Temperature	150	$^{\circ}$	
T <sub>stg</sub>	Storage Temperature	-40~150	$^{\circ}$	







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### **ELECTRICAL CHARACTERISTICS**

Tj=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = -5mA; R <sub>BE</sub> = ∞	-120			V
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	$I_{C}$ = -50mA; $R_{BE}$ = $\infty$	-120			V
V <sub>(BR)CBO</sub>	Collector-Base Breakdown Voltage	I <sub>C</sub> = -5mA; I <sub>E</sub> = 0	-150			V
V <sub>(BR)EBO</sub>	Emitter-Base Breakdown Voltage	I <sub>E</sub> = -5mA; I <sub>C</sub> = 0	-6			V
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = -5A; I <sub>B</sub> = -0.5A		-0.6		V
V <sub>BE(on)</sub>	Base-Emitter On Voltage	I <sub>C</sub> = -1A; V <sub>CE</sub> = -5V			-1.5	V
Ісво	Collector Cutoff Current	V <sub>CB</sub> = -80V; I <sub>E</sub> = 0			-0.1	mA
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = -4V; I <sub>C</sub> = 0			-0.1	mA
h <sub>FE</sub>	DC Current Gain	I <sub>C</sub> = -1A; V <sub>CE</sub> = -5V	40		320	
f <sub>T</sub>	Current-Gain—Bandwidth Product	I <sub>C</sub> = -1A; V <sub>CE</sub> = -5V		15		MHz

### ♦ h<sub>FE</sub> Classifications

С	D	E	F
40-80	60-120	100-200	160-320

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